

Progress in VECSEL technology for laser guide stars

Jussi-Pekka Penttinen^{1,2}, Emmi Kantola^{1,2}, Sanna Ranta^{1,2}, Mika Mäki^{1,2}, and Mircea Guina^{1,2}

¹Vexlum Ltd. Korkeakoulunkatu 3, 33720 Tampere, Finland

²Optoelectronics Research Centre, Tampere University, Finland

contact@vexlum.com, www.vexlum.com

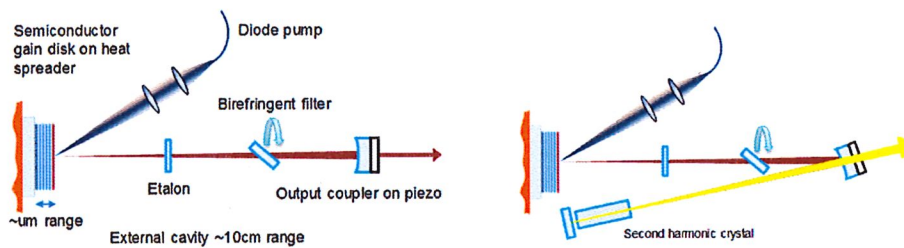


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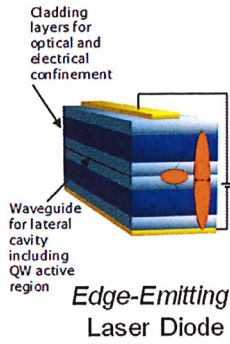


VECSEL

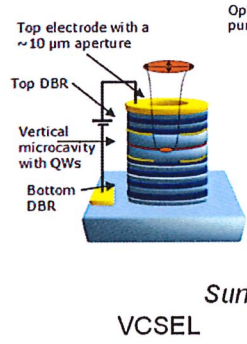
- Vertical External-Cavity Surface-Emitting Laser
 - Kuznetsov, M., et al. *IEEE Photonics Technology Letters* 9.8 (1997): 1063-1065.
 - M. Guina et al, "Optically pumped VECSELs: review of technology and progress" *J. Phys. D: Appl. Phys.*, 2017, 50, p. 3830001
- Also known as SDL (Semiconductor Disk Laser) or OPSL (Optically Pumped Semiconductor Laser)
- Main features
 - High brightness
 - High power
 - Wavelength versatility
 - Compact
 - Robust
 - Efficient frequency conversion



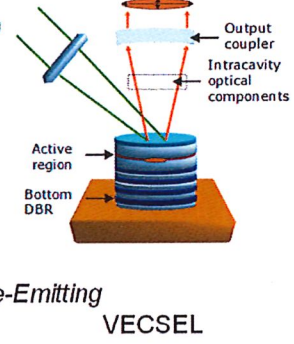
Comparison with other semiconductor lasers



Power level: <10 W per emitter
Beam quality: poor
Wavelength range: broad
Size: mm range



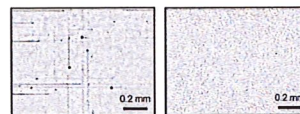
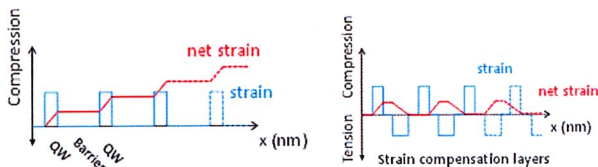
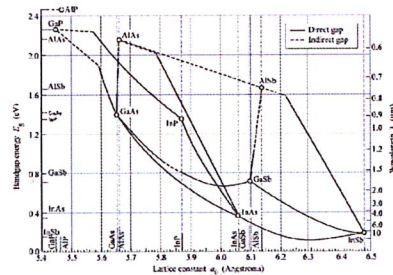
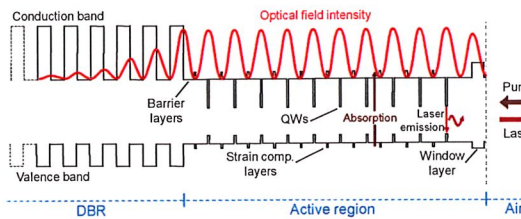
Power level: 1 - 10 mW
Beam quality: excellent
Wavelength range: narrow (DBR limited)
Size: mm range



Power level: up to 100 W
Beam quality: good-excellent
Wavelength range: very broad (efficient SHG)
Size: tens of cm

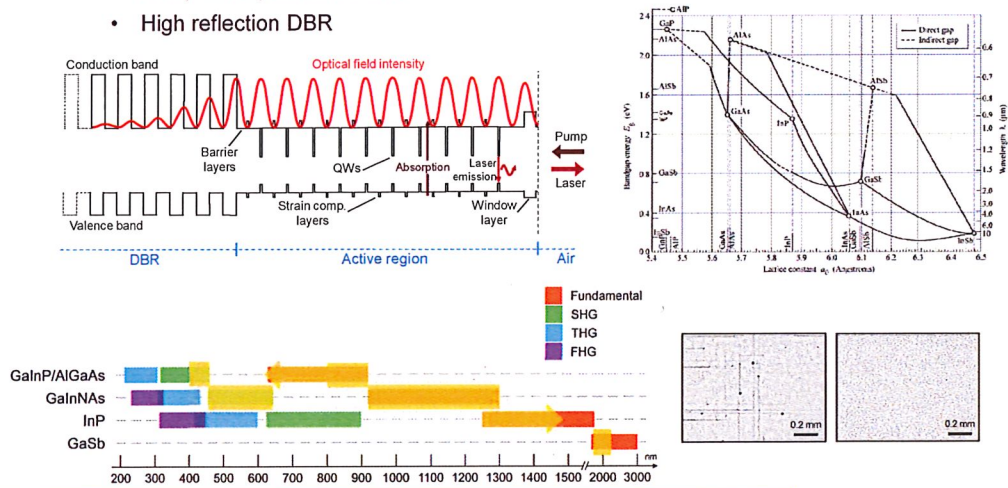
Semiconductor materials engineering

- Wavelength is defined by the band gap of the quantum wells
 - Pump absorption in barriers
 - High reflection DBR



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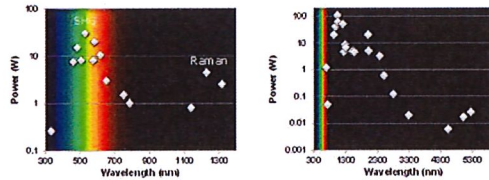
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Power scaling



General trend of output powers vs. wavelength covered by major types of VCSEL technologies

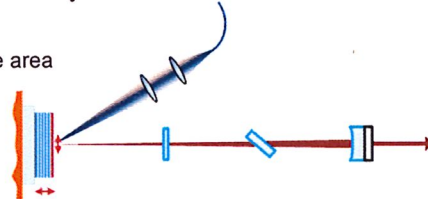
- By increasing the volume of the amplifying medium

Longitudinal power scaling

- Increasing the thickness of the lasing material by
 - adding more quantum wells in one gain mirror – limit from pump absorption and strain
 - adding more gain mirrors into the cavity - talk by Michael Hart next

Lateral power scaling by increasing the surface area

- increasing the pump spot and the mode size on the gain mirror
- thermal management important



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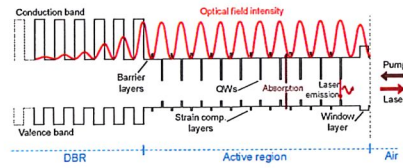
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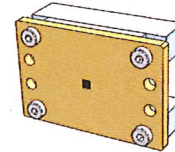
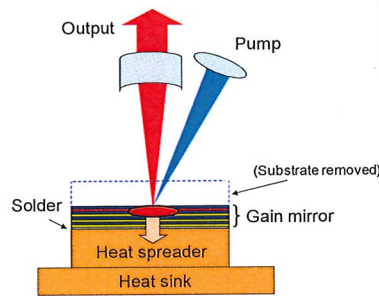
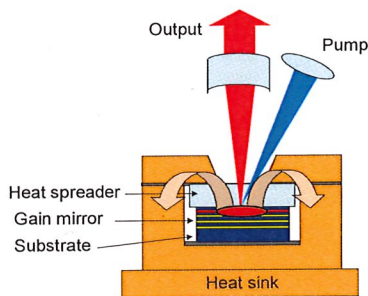
Thermal management

- Removal of the excess heat from optical pumping
- Two main approaches



Intra-cavity cooling

Flip-chip cooling



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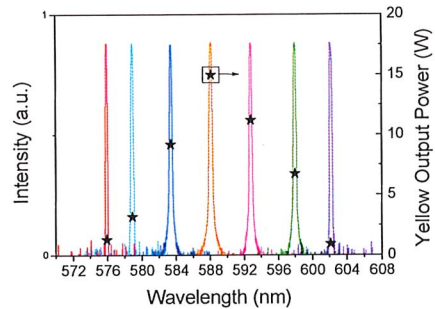
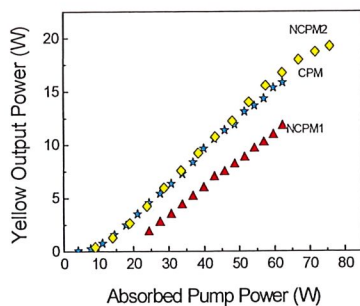
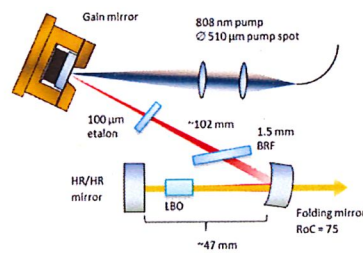
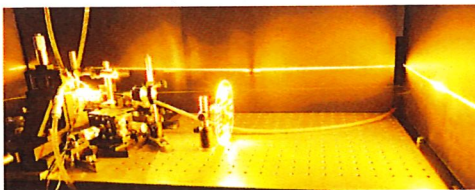
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20 W @ 589 nm (from ~20 W @ 1178 nm)

E. Kantola et al. *Optics Express* 22.6 (2014): 6372-6380.



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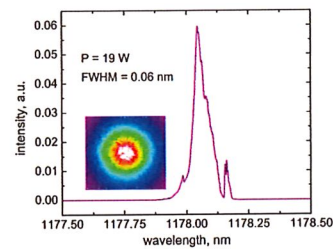
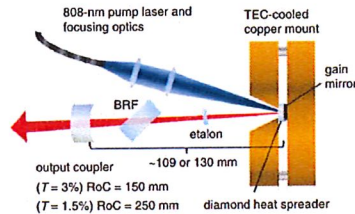
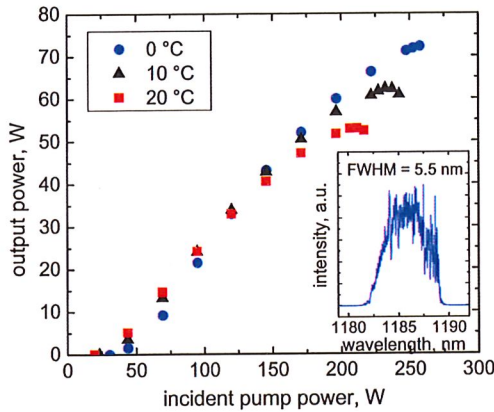
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72 W @ 1178 nm

E. Kantola et al. Electronics Letters 54.19 (2018): 1135-1137.



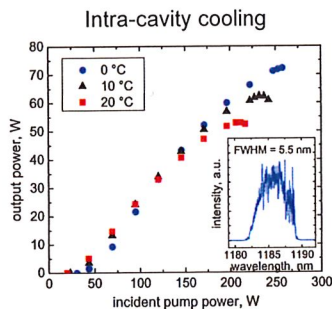
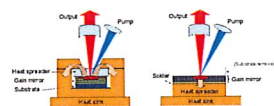
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High-efficiency 1178 nm flip-chip



Temperature set point	°C	20	Temperature setpoint	°C	20	% of top emitter
Max output power	W	53	Max output power	W	49.5	93.3
Incident pump power	W	211	Incident pump power	W	130.1	61.6
Optical-to-optical efficiency	%	25	Opt-to-opt efficiency	%	38.0	152
Slope efficiency	%	33	Slope efficiency	%	45.7	138

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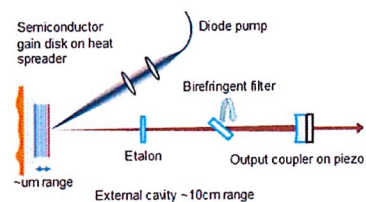
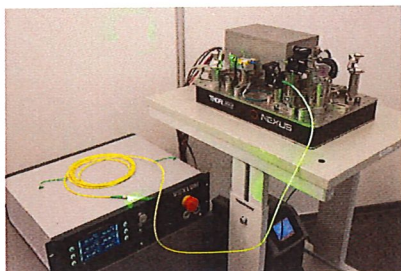
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Progress in systems development

- **VALO SF** – robust multiwatt single-frequency infrared VECSEL
 - 100 kHz linewidth, excellent beam, up 10 THz tuning range
 - Turn-key setup with control electronics, tunable with cavity piezo



- In the next few months: first multiwatt visible single-frequency VECSEL – **VALO SHG**
- Continue with **power scaling of VALO SHG** with target >10 W 589

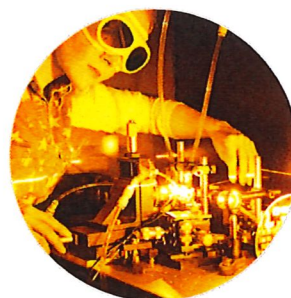
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Summary

- VECSELs are the most versatile laser systems
- Progress in 1178 nm gain mirror technology thanks to
 - 50% Improvements in the semiconductor structure
 - 50% Improvements in thermal management
- VEXLUM is a VECSEL company
 - Lasers and gain mirrors with wavelengths on demand
 - Specialized in high-power 1178 nm
 - Focus on systems development for high power 589 nm



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Thank you!

jp@vexlum.com, www.vexlum.com



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